# NSN 5962-01-033-5503

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## **Body Length:**

Between 0.747 inches and 0.815 inches

## Body Width:

Between 0.220 inches and 0.280 inches

# **Body Height:**

0.200 inches

**Maximum Power Dissipation Rating:** 

525.0 milliwatts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+200.0 degrees celsius

## End Application:

Building block 57 fscm 30003

## **Features Provided:**

Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and high speed and wire-or outputs

#### Inclosure Material:

Ceramic and glass

## Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

#### **Time Rating Per Chacteristic:**

60.00 nanoseconds propagation delay time, low to high level output

## Memory Device Type:

Rom

#### **Precious Material And Location:**

Terminals gold

#### **Test Data Document:**

06424-10560 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Terminal Type And Quantity:**

16 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

